

/ Descriptions

KF \$0) GE G Silicon PNP transistor in a TO-92 Plastic Package.

/ Features

Low Leakage current, Low collector saturation voltage.

/ Applications

General amplifier.

/ Equivalent Circuit



/ Pinning



PIN1 Collector PIN 2 Base PIN 3 Emitter

/ hFE Classifications & Marking

See Marking Instructions

/ Absolute Maximum Ratings(Ta=25)

| Parameter | Symbol | Rating | Unit |
|--------------------------------|-----------|---------|------|
| Collector to Base Voltage | V_{CBO} | -60 | V |
| Collector to Emitter Voltage | V_{CEO} | -60 | V |
| Emitter to Base Voltage | V_{EBO} | -5.0 | V |
| Collector Current - Continuous | I_C | -600 | mA |
| Collector Power Dissipation | P_C | 625 | mW |
| Junction Temperature | T_j | 150 | |
| Storage Temperature Range | T_{stg} | -55 150 | |

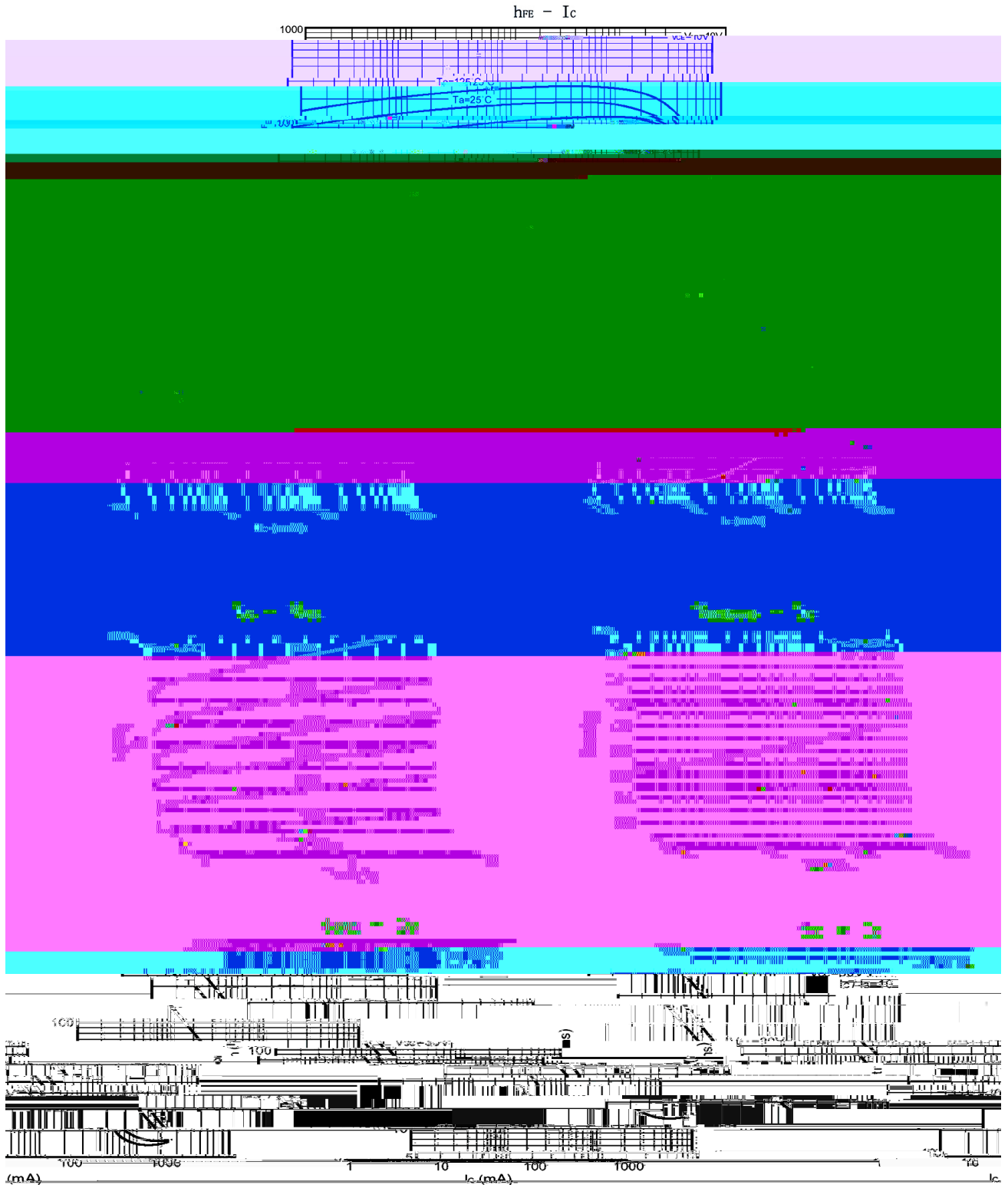
/ Electrical Characteristics(Ta=25)

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Unit |
|--|-------------------|---|------|-----|------|---------|
| Collector to Base Breakdown Voltage | V_{CBO} | $I_C=-10\mu A$ $I_E=0$ | -60 | | | V |
| Collector to Emitter Breakdown Voltage | V_{CEO} | $I_C=-10mA$ $I_B=0$ | -60 | | | V |
| Emitter to Base Breakdown Voltage | V_{EBO} | $I_E=-10\mu A$ $I_C=0$ | -5.0 | | | V |
| Collector Cut-Off Current | I_{CBO} | $V_{CB}=-50V$ $I_E=0$ | | | -0.1 | μA |
| DC Current Gain | $h_{FE(1)*}$ | $V_{CE}=-10V$ $I_C=-150mA$ | 100 | | 300 | |
| | $h_{FE(2)*}$ | $V_{CE}=-10V$ $I_C=-500mA$ | 50 | | | |
| | $h_{FE(3)}$ | $V_{CE}=-10V$ $I_C=-10mA$ | 100 | | | |
| | $h_{FE(4)}$ | $V_{CE}=-10V$ $I_C=-1.0mA$ | 100 | | | |
| | $h_{FE(5)}$ | $V_{CE}=-10V$ $I_C=-0.1mA$ | 75 | | | |
| Collector-Emitter Saturation Voltage | $V_{CE(sat)(1)*}$ | $I_C=-150mA$ $I_B=-15mA$ | | | -0.4 | V |
| | $V_{CE(sat)(2)*}$ | $I_C=-500mA$ $I_B=-50mA$ | | | -1.6 | V |
| Base-Emitter Saturation Voltage | $V_{BE(sat)(1)*}$ | $I_C=-150mA$ $I_B=-15mA$ | | | -1.3 | V |
| | $V_{BE(sat)(2)*}$ | $I_C=-500mA$ $I_B=-50mA$ | | | -2.6 | V |
| Transition Frequency | f_T | $V_{CE}=-20V$ $I_C=-50mA$ $f=100MHz$ | 200 | | | MHz |
| Collector Output Capacitance | C_{ob} | $V_{CB}=-10V$ $I_E=0$ $f=0.1MHz$ | | | 30 | pF |
| Turn-On Time | T_{on} | $V_{CC}=-30V$ $V_{BE(off)}=-1.5V$ $I_C=-150mA$ $I_{B1}=-15mA$ | | | 0.05 | μs |
| Turn-Off Time | T_{off} | $V_{CC}=-30V$ $I_C=-150mA$ $I_{B1}=I_{B2}=-15mA$ | | | 0.1 | μs |

*Pulse test: pulse width 300 μs , duty cycle 2.0%

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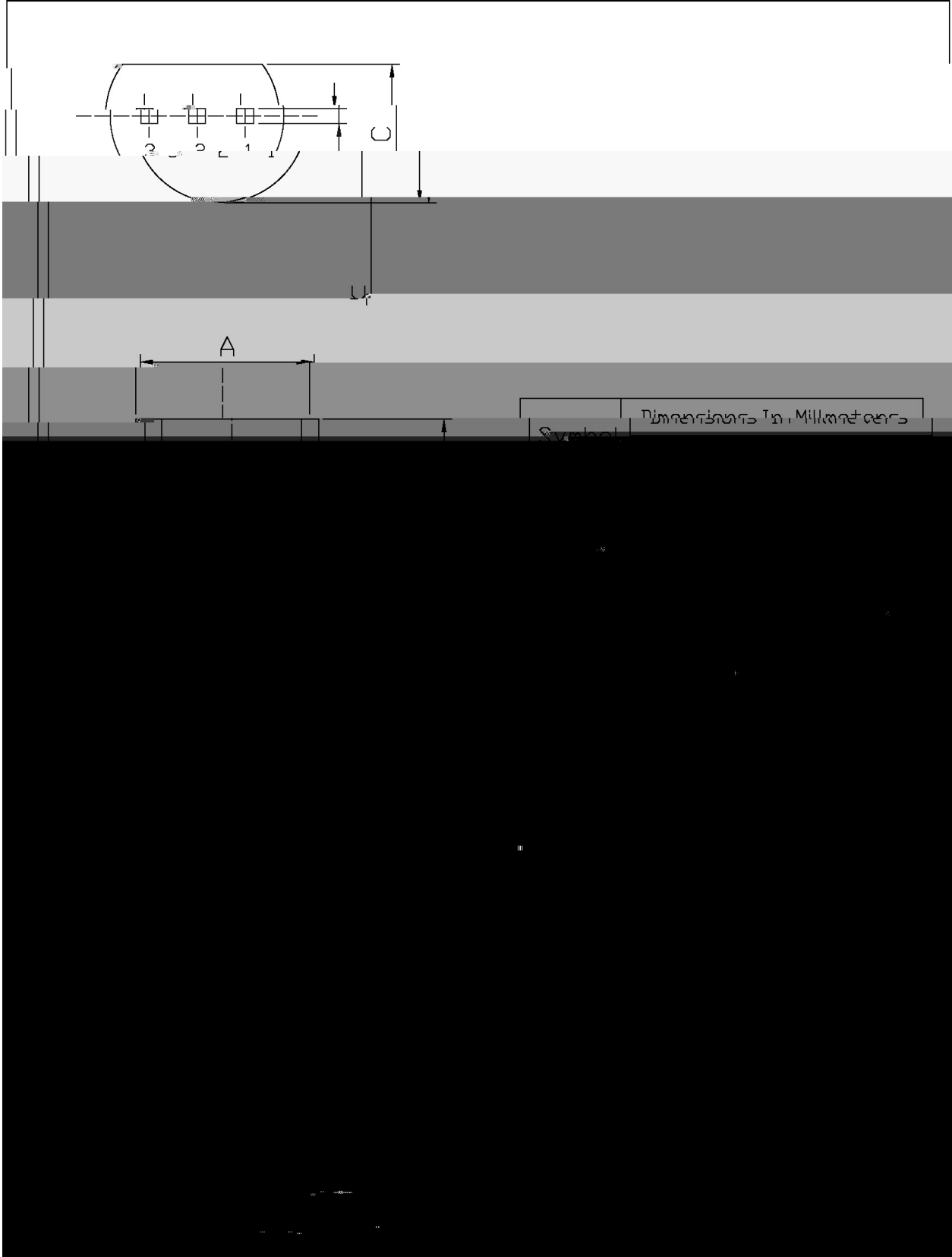
/ Electrical Characteristic Curve



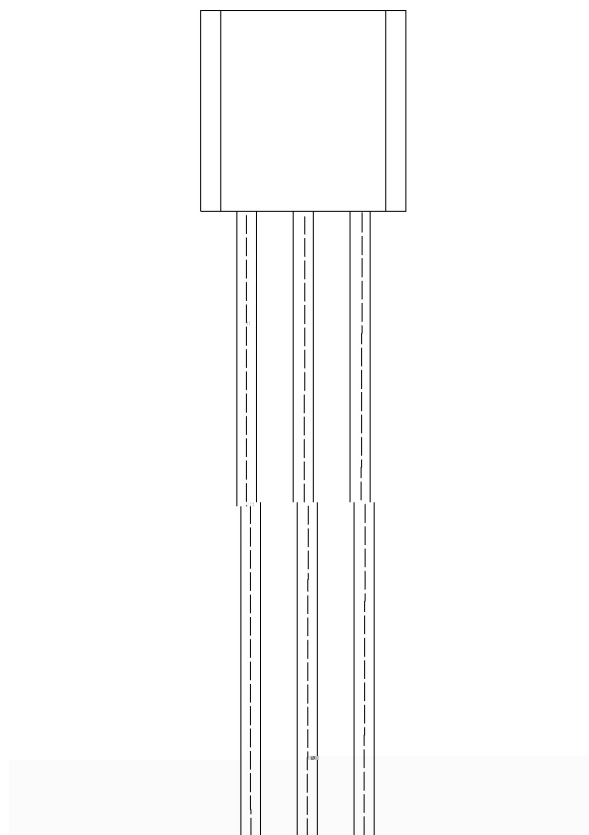
/ Package Dimensions

TO-92

Unit: mm



/ Marking Instructions



() / Temperature Profile for Dip Soldering(Pb-Free)



| | | | | | | |
|---|--------|-----|------------|--------|---|--------------------------------------|
| 1 | 25 | 150 | 60 | 90sec; | Note: | 1.Preheating:25~150 , Time:60~90sec. |
| 2 | 255..5 | | 5..0.5sec; | | 2.Peak Temp.:255..5 , Duration:5..0.5sec. | |
| 3 | | 2 | 10 | /sec. | 3. Cooling Speed: 2~10 /sec. | |

/ Resistance to Soldering Heat Test Conditions

270..5 10..1 sec. Temp:270±5 Time:10±1 sec

/ Packaging SPEC.

/ BULK

Fig. 17-10-6 U31, Tf0.55 0.942.6110l1e7.2TT4 5sec.